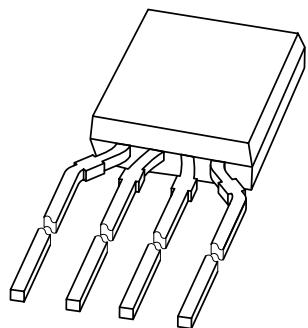


# DATA SHEET



## **KMZ10A1** Magnetic field sensor

Product specification

1998 Apr 06

Supersedes data of 1996 Nov 14

File under Discrete Semiconductors, SC17

**Magnetic field sensor****KMZ10A1****DESCRIPTION**

The KMZ10A1 is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. Its properties enable this sensor to be used in a wide range of applications such as navigation, current and earth magnetic field measurement etc. The special arrangement of the sensing chip allows the construction of coils for switching the auxiliary field ( $H_x$ ) along the length axis of the sensor. The sensor can be operated at any frequency between DC and 1 MHz.

**PINNING**

PIN	SYMBOL	DESCRIPTION
1	+ $V_O$	output voltage
2	GND	ground
3	- $V_O$	output voltage
4	$V_{CC}$	supply voltage

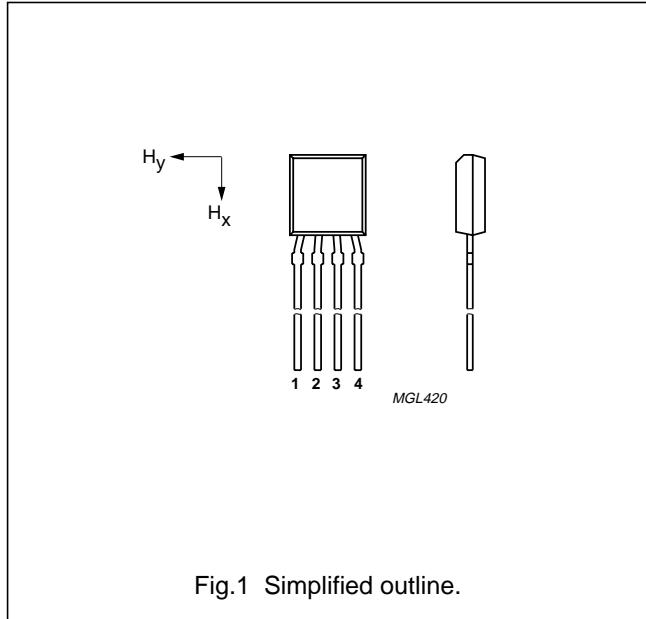


Fig.1 Simplified outline.

**QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
$V_{CC}$	DC supply voltage	–	5	–	V
$H_y$	magnetic field strength	-0.5	–	+0.5	kA/m
$H_x$	auxiliary field	–	0.5	–	kA/m
S	sensitivity	–	14	–	$\frac{mV/V}{kA/m}$
$S_s$	sensitivity (with switched $H_x$ )	–	22	–	$\frac{mV/V}{kA/m}$
$R_{bridge}$	bridge resistance	0.85	–	1.75	$k\Omega$
$V_{offset}$	offset voltage	-1.5	–	+1.5	mV/V

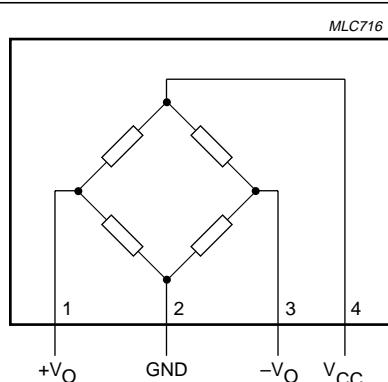
**CIRCUIT DIAGRAM**

Fig.2 Simplified circuit diagram.

## Magnetic field sensor

KMZ10A1

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	DC supply voltage		–	9	V
$P_{tot}$	total power dissipation	up to $T_{amb} = 132^{\circ}\text{C}$	–	100	mW
$T_{stg}$	storage temperature		–65	+150	$^{\circ}\text{C}$
$T_{bridge}$	bridge operating temperature		–40	+150	$^{\circ}\text{C}$

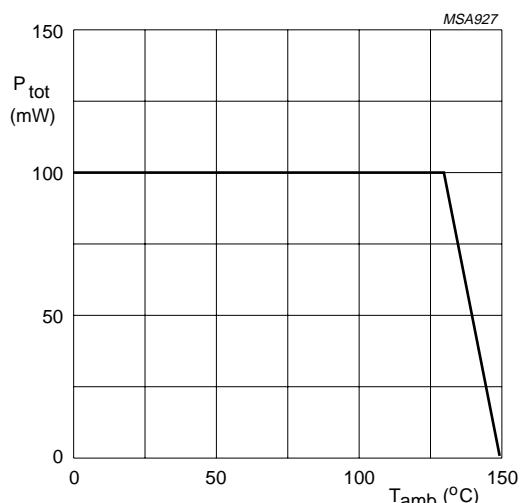


Fig.3 Power derating curve.

## Magnetic field sensor

KMZ10A1

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	180	K/W

## CHARACTERISTICS

 $T_{amb} = 25^\circ C$  and  $H_x = 0.5 \text{ kA/m}$  unless otherwise specified; see notes 1 and 2.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{CC}$	DC supply voltage		–	5	–	V
$H_y$	operating range	note 2	–0.5	–	+0.5	kA/m
$S$	sensitivity	open circuit; notes 2 and 3	11	–	17	$\frac{\text{mV/V}}{\text{kA/m}}$
$TCV_O$	temperature coefficient of output voltage at constant supply voltage	$V_{CC} = 5 \text{ V};$ $T_{amb} = -25 \text{ to } +125^\circ C$	–	–0.4	–	%/K
$VCV_O$	temperature coefficient of output voltage at constant supply current	$I_B = 3 \text{ mA};$ $T_{amb} = -25 \text{ to } +125^\circ C$	–	–0.15	–	%/K
$R_{bridge}$	bridge resistance		0.85	–	1.75	$\text{k}\Omega$
$TCR_{bridge}$	temperature coefficient of bridge resistance	$T_j = -25 \text{ to } +125^\circ C$	–	0.25	–	%/K
$V_{offset}$	offset voltage		–1.5	–	+1.5	mV/V
$TCV_{offset}$	offset voltage drift	$T_{bridge} = -25 \text{ to } +125^\circ C$	–6	–	+6	$\frac{\mu\text{V/V}}{\text{K}}$
$FL$	linearity deviation of output voltage	$H_y = 0 \text{ to } \pm 0.25 \text{ kA/m}^{-1}$	–	–	0.8	%·FS
		$H_y = 0 \text{ to } \pm 0.4 \text{ kA/m}^{-1}$	–	–	2.5	%·FS
		$H_y = 0 \text{ to } \pm 0.5 \text{ kA/m}^{-1}$	–	–	4.0	%·FS
$FH$	hysteresis of output voltage		–	–	0.5	%·FS
$f$	operating frequency		0	–	1	MHz

Characteristics with  $H_x = 0$  (switched  $H_x$ , see note 4);  $V_{CC} = 5 \text{ V}$ 

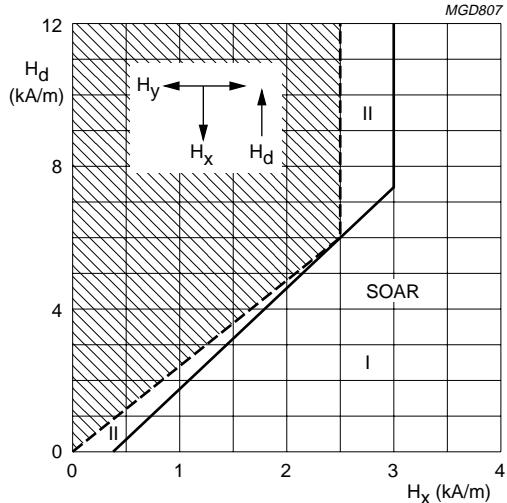
$H_y$	operating range	note 2	–0.05	–	+0.05	kA/m
$S_s$	sensitivity	slope between $H_y = 0$ and $H_y = 40 \text{ A/m}$	14	–	27	$\frac{\text{mV/V}}{\text{kA/m}}$

## Notes

1. Before first operation or after operation outside the SOAR (Fig.4) the sensor has to be reset by application of an auxiliary field  $H_x = 3 \text{ kA/m}$ .
2. No disturbing field ( $H_d$ ) allowed; for stable operation under disturbing conditions see Fig.4 (SOAR) and see Fig.5 for decrease of sensitivity.
3. Sensitivity measured as  $\Delta V_O / \Delta H_y$  between  $H_y = 0$  and  $H_y = 0.4 \text{ kA/m}$ .
4. See application information.

## Magnetic field sensor

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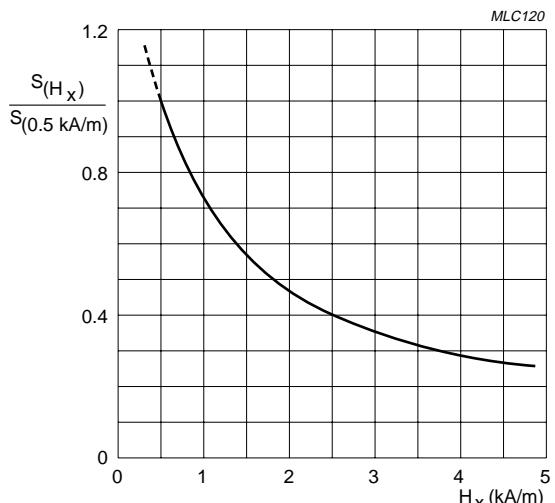


I = Region of permissible operation.

II = Permissible extension if  $H_y < 0.05$  kA/m.

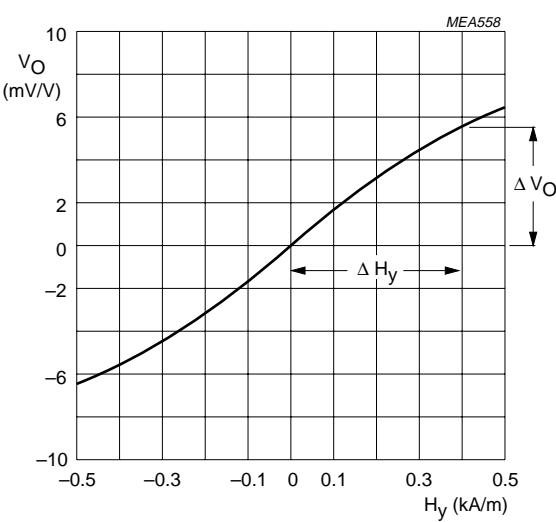
In applications with  $H_x < 3$  kA/m, the sensor has to be reset, after leaving the SOAR, by an auxiliary field of  $H_x = 3$  kA/m.

Fig.4 Safe Operating Area (permissible disturbing field  $H_d$  as a component of auxiliary field  $H_x$ ).



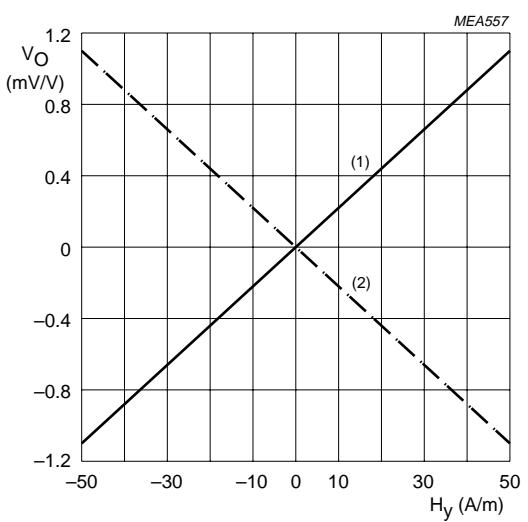
In applications with  $H_x \leq 3$  kA/m, the sensor has to be reset by an auxiliary field of  $H_x = 3$  kA/m before use.

Fig.5 Relative sensitivity (ratio of sensitivity at certain  $H_x$  and sensitivity at  $H_x = 0.5$  kA/m).



$H_x = 0.5$  kA/m;  $T_{\text{amb}} = 25$  °C;  $V_{\text{offset}} = 0$ ;  $S = \Delta V_O / \Delta H_y$ .

Fig.6 Sensor output characteristics.



(1) Sensor reset with  $H_x = 3$  kA/m.

(2) Sensor reset with  $H_x = -3$  kA/m.

Fig.7 Output characteristic with  $H_x = 0$  (switched  $H_x$ ).

## Magnetic field sensor

**KMZ10A1**

### APPLICATION INFORMATION

A problem with measuring weak magnetic fields is that precision is limited by drift in both the sensor and amplifier offset. In these instances, it is possible to take advantage of the 'flipping' characteristics of the KMZ10 series to generate an output that is independent of offset. The sensor, located in a coil connected to a current pulse generator producing magnetic field pulses periodically reversed by alternate positive and negative going current pulses, is continually flipped from its normal to its reversed polarity and back again. The polarity of the offset however, remains unchanged, so the offset itself can be eliminated by passing the output signal through a filter circuit.

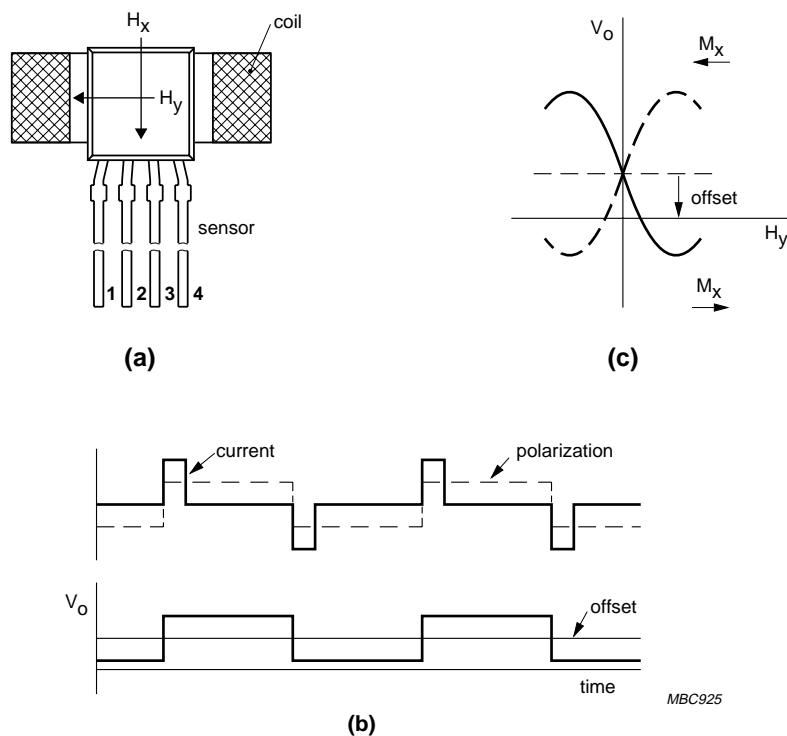


Fig.8 Measuring weak magnetic fields with the KMZ10A1.

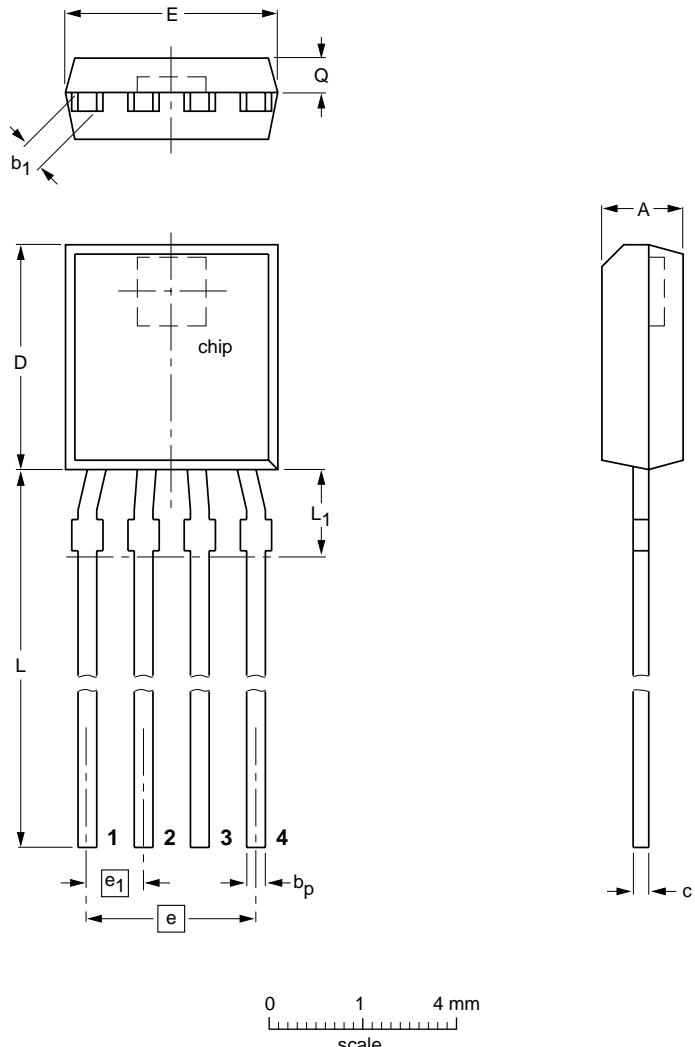
## Magnetic field sensor

KMZ10A1

## PACKAGE OUTLINE

Plastic single-ended flat package; 4 in-line leads

SOT195



## DIMENSIONS (mm are the original dimensions)

UNIT	A	b <sub>p</sub>	b <sub>1</sub>	c	D	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.	Q
mm	1.8 1.6	0.48 0.40	0.7 0.5	0.45 0.39	5.2 5.0	4.8 4.4	3.75	1.25	14.5 12.7	2	0.8 0.7

## Notes

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT195						97-06-02

## Magnetic field sensor

KMZ10A1

### DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

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Magnetic field sensor

KMZ10A1

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**NOTES**

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**NOTES**

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**NOTES**

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